



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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SOT23 SILICON PLANAR DUAL SCHOTTKY BARRIER DIODES

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BAS70-04
BAS70-05
BAS70-06

			 SOT23
SERIES PAIR	COMMON CATHODE	COMMON ANODE	
Device Type: BAS70-04	Device Type: BAS70-05	Device Type: BAS70-06	
Partmarking Detail: 2Z	Partmarking Detail: 2Z5	Partmarking Detail: 1Z	

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation at $T_{amb}=25^{\circ}\text{C}$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Breakdown Voltage	V_{BR}	70		V	$I_R=10\mu\text{A}$
Reverse Leakage Current	I_R		200	nA	$V_R=50\text{V}$
Forward Voltage	V_F		410	mV	$I_F=1\text{mA}$
Forward Current	I_F	15		mA	$V_F=1\text{V}$
Capacitance	C_T		2.0	pF	$f=1\text{MHz}, V_R=0$
Effective Minority Lifetime (1)	τ		100	ps	$f=54\text{MHz}, I_{pk}= 20\text{mA}$ (Krakauer Test Method)

(1) Sample Test

For typical characteristics graphs see ZC2800E datasheet.